

DB Plastic-Encapsulate Bridge Rectifier

Features

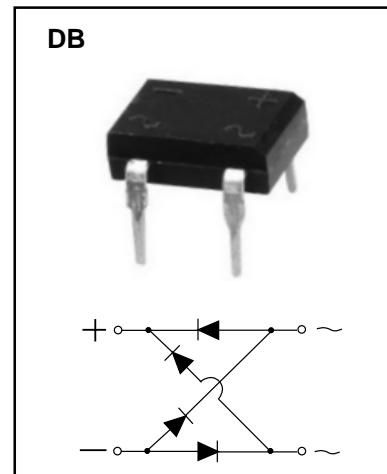
- I_o 2.0A
- V_{RRM} 50V-1000V
- High surge current capability
- Glass passivated chip
- Polarity: Color band denotes cathode

Applications

- General purpose 1 phase Bridge rectifier applications

Marking

- DB20X
- X : From 1 To 7



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Conditions	DB2							
				01	02	03	04	05	06	07	
Repetitive Peak Reverse Voltage	V_{RRM}	V		50	100	200	400	600	800	1000	
Maximum RMS Voltage	V_{RMS}	V		35	70	140	280	420	560	700	
Average Rectified Output Current	I_o	A	60Hz sine wave, R-load, $T_a=25^\circ C$								2.0
Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz sine wave, 1 cycle, $T_j=25^\circ C$								60
Current Squared Time	I^2t	A^2S	$1ms \leq t < 8.3ms$, $T_j=25^\circ C$, Rating of per diode								15
Storage Temperature	T_{stg}	$^\circ C$									-55 ~+150
Junction Temperature	T_j	$^\circ C$									-55 ~+150

Electrical Characteristics ($T_a=25^\circ C$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition	Max
Peak Forward Voltage	V_{FM}	V	$I_{FM}=2.0A$, Pulse measurement, Rating of per diode	1.1
Peak Reverse Current	I_{RRM}	μA	$V_{RM}=V_{RRM}$, Pulse measurement, Rating of per diode	10
Thermal Resistance	$R_{\theta J-A}$	$^\circ C/W$	Between junction and ambient, On glass-epoxy substrate	68
	$R_{\theta J-L}$		Between junction and lead	15

Typical Characteristics

FIG1:Io-Ta Curve

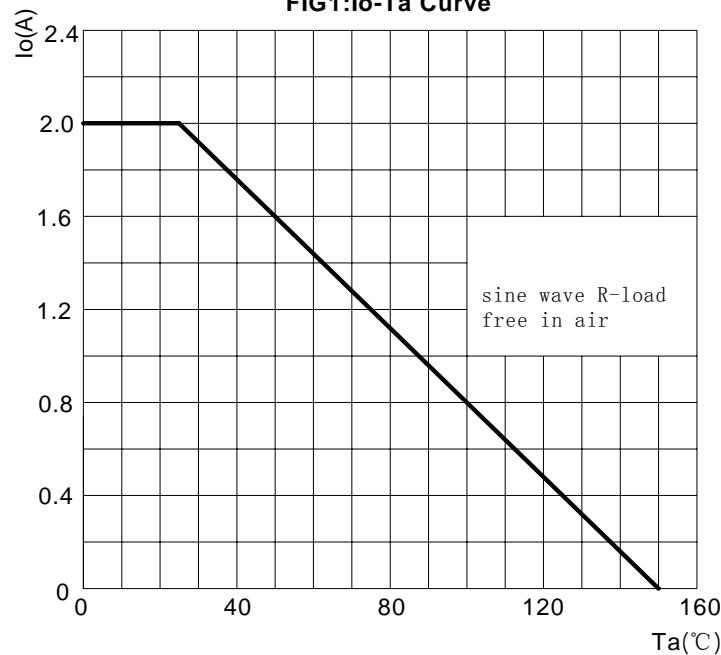


FIG2: Surge Forward Current Capability

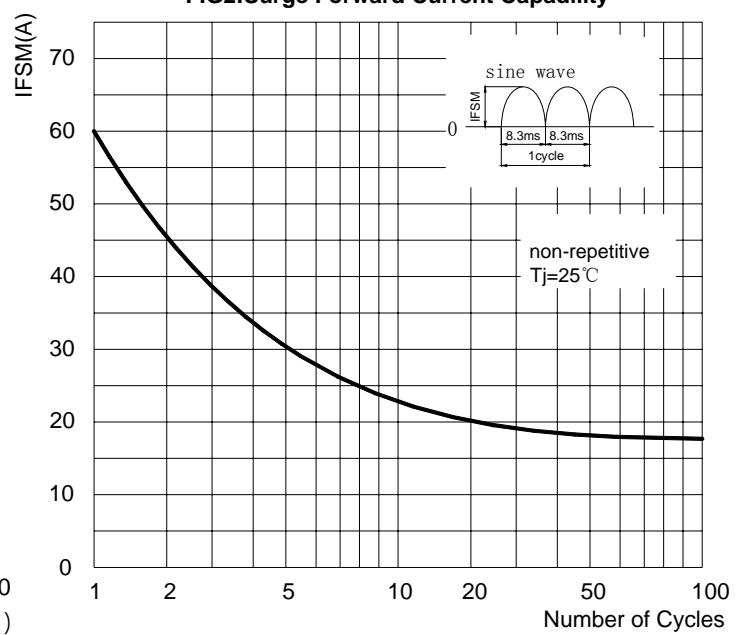


FIG3: Forward Voltage

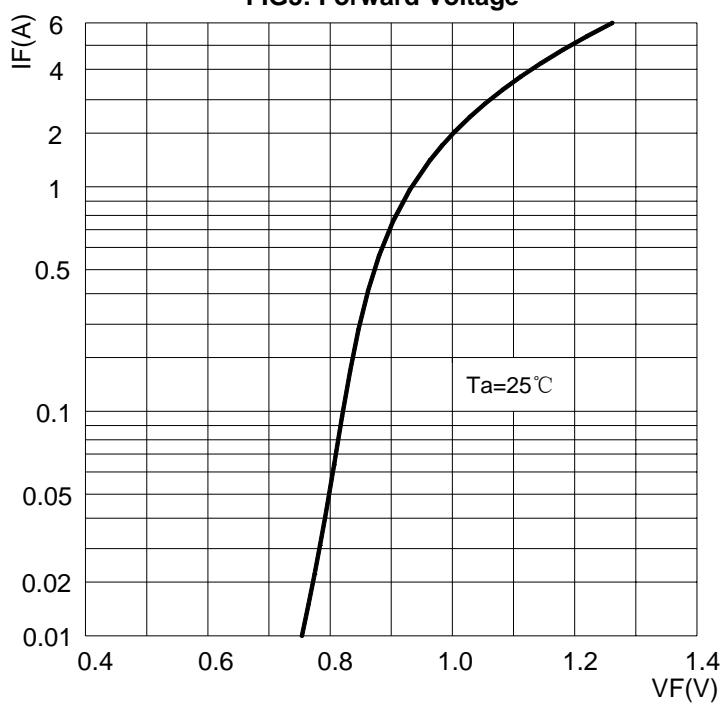
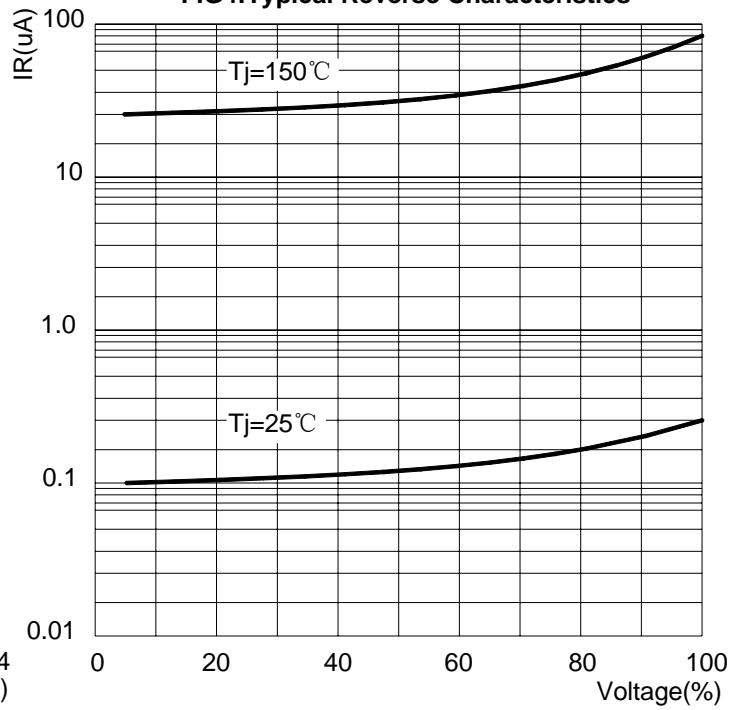
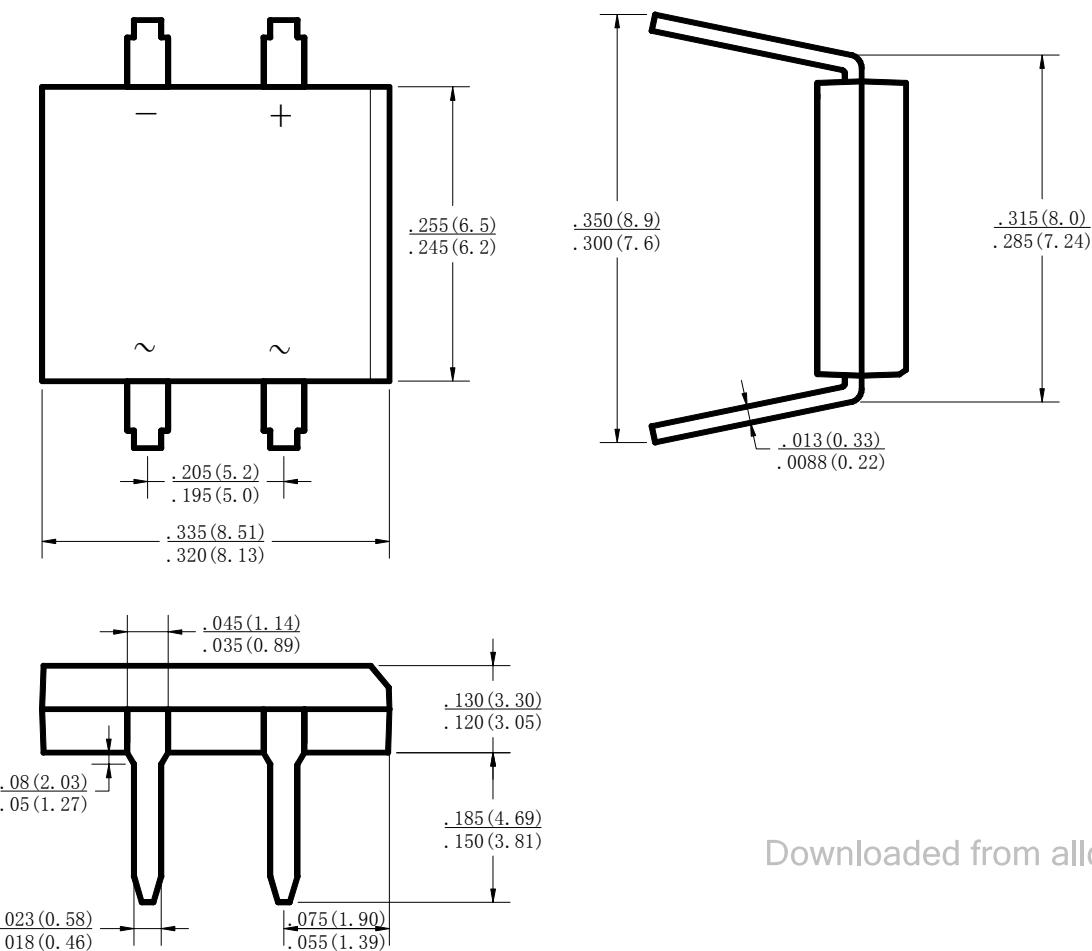


FIG4: Typical Reverse Characteristics



Downloaded from alldatasheet.com

DB Package Outline Dimensions



Downloaded from alldatasheet.com

Dimensions in inches and (millimeters)

NOTICE

JSHD reserve the right to make modifications,enhancements, improvements, corrections or other changes without further notice to any product herein.JSHD does not assume any liability arising out of the application or use of any product described herein.